Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
Between 0.766 inches and 0.792 inches
Overall Diameter:
Between 0.228 inches and 0.232 inches
Mounting Method:
Terminal
Semiconductor Material:
Silicon
Current Rating Per Characteristic:
30.00 milliamperes all primaries preset
Power Rating Per Characteristic:
2.0 watts forward power dissipation, dc pascal
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius ambient air
Terminal Type And Quantity:
2 solder stud
Specification Data:
07690-438238 manufacturers source control
Shelf Life:
N/a
Unit Of Measure:
-
Demilitarization:
No
Fiig:
A110a0